Rectifier diodes ultrafast, rugged

BYV42E series

GENERAL DESCRIPTION

Glass passivated high efficiency rugged dual rectifier diodes in a plastic envelope, featuring low forward voltage drop, ultra-fast recovery times and soft recovery characteristic. These devices can withstand reverse voltage transients and have guaranteed reverse surge and ESD capability. They are intended for use in switched mode power supplies and high frequency circuits in general where low conduction and switching losses are essential.

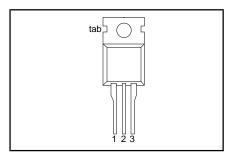
QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	MAX.	MAX.	UNIT
V_{RRM}	BYV42E- Repetitive peak reverse voltage	100 100	150 150	200 200	V
$I_{O(AV)}$	Forward voltage Output current (both diodes conducting)	0.85 30	0.85 30	0.85 30	V A
t _{rr} I _{RRM}	Reverse recovery time Repetitive peak reverse current per diode	28 0.2	28 0.2	28 0.2	ns A

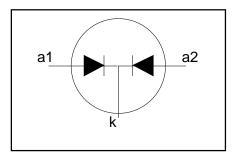
PINNING - TO220AB

PIN	DESCRIPTION
1	anode 1 (a)
2	cathode (k)
3	anode 2 (a)
tab	cathode (k)

PIN CONFIGURATION



SYMBOL



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.		MAX.		UNIT
V _{RRM} V _{RWM} V _R	Repetitive peak reverse voltage Crest working reverse voltage Continuous reverse voltage		- - -	-100 100 100 100	-150 150 150 150	-200 200 200 200	V V
I _{O(AV)}	Output current (both diodes conducting) ²	square wave $\delta = 0.5$; $T_{mb} \le 108$ °C sinusoidal $a = 1.57$; $T_{mb} \le 111$ °C	-		30 27		A A
I _{O(RMS)} I _{FRM}	RMS forward current Repetitive peak forward current per diode	$t = 25 \mu s; δ = 0.5;$ $T_{mb} \le 108 °C$	-		43 30		A A
I _{FSM}	Non-repetitive peak forward current per diode	t = 10 ms t = 8.3 ms sinusoidal; with reapplied V _{RWM(max)}	-		150 160		A A
l ² t	I ² t for fusing	t = 10 ms	-		112		A ² s
I _{RRM}	Repetitive peak reverse current per diode	,	-		0.2		A
I _{RSM}	Non-repetitive peak reverse current per diode	$t_{p} = 100 \ \mu s$	-		0.2		Α
$egin{array}{c} T_{stg} \ T_{j} \end{array}$	Storage temperature Operating junction temperature		-40 -		150 150		ů. Č

¹ $T_{mb} \le 144$ °C for thermal stability.

For output currents in excess of 20 A, connection should be made to the exposed metal mounting base.

² Neglecting switching and reverse current losses.

BYV42E series

ESD LIMITING VALUE

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _C	j s	Human body model; C = 250 pF; R = 1.5 kΩ	-	8	kV

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$R_{\text{th j-mb}}$ $R_{\text{th j-a}}$	mounting base	per diode both diodes conducting in free air	1 1 1	- - 60	2.4 1.4 -	K/W K/W K/W

STATIC CHARACTERISTICS

 $T_i = 25$ °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _F	Forward voltage (per diode)	$I_F = 15 \text{ A}; T_j = 150^{\circ}\text{C}$	-	0.78	0.85	V
		I _F = 15 A	-	0.95	1.05	V
		$I_{\rm F} = 30 \text{ A}$	-	1.00	1.20	V
I _R	Reverse current (per diode)	$\dot{V}_R = V_{RWM}$; $T_i = 100 ^{\circ}C$	-	0.5	1	mΑ
	, ,	$V_R = V_{RWM}$	-	10	100	μΑ

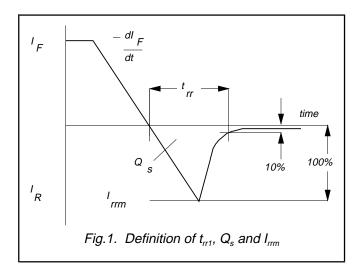
DYNAMIC CHARACTERISTICS

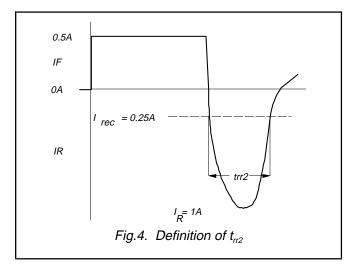
T_i = 25 °C unless otherwise stated

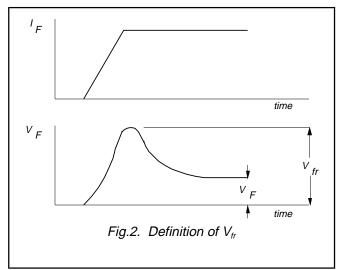
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Q _s	Reverse recovery charge (per diode)	$I_F = 2 \text{ A}; V_R \ge 30 \text{ V}; -dI_F/dt = 20 \text{ A}/\mu\text{s}$	-	6	15	nC
t _{rr1}	Reverse recovery time (per diode)	$I_F = 1 \text{ A}; V_R \ge 30 \text{ V};$ - $dI_F/dt = 100 \text{ A/}\mu\text{s}$	-	20	28	ns
t _{rr2}	Reverse recovery time (per diode)	$I_{\rm F} = 0.5 \text{ A to } I_{\rm R} = 1 \text{ A}; I_{\rm rec} = 0.25 \text{ A}$	-	13	22	ns
V _{fr}	Forward recovery voltage (per diode)	$I_F = 1 \text{ A}; dI_F/dt = 10 \text{ A/}\mu\text{s}$	-	1	1	V

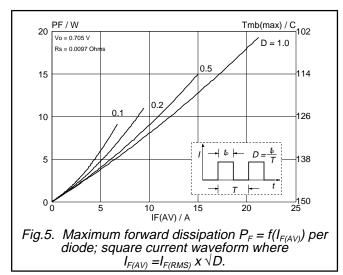
Rectifier diodes ultrafast, rugged

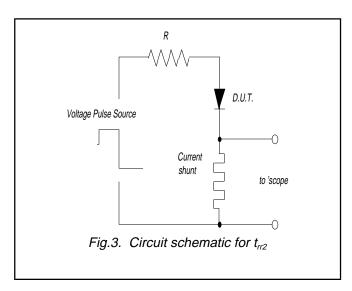
BYV42E series

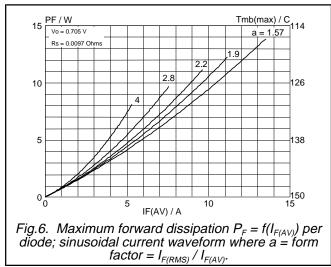






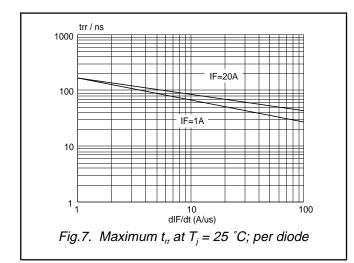






Rectifier diodes ultrafast, rugged

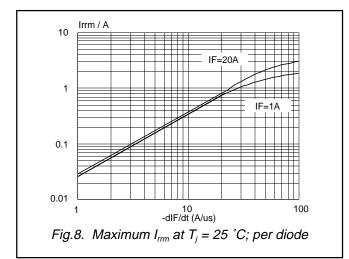
BYV42E series

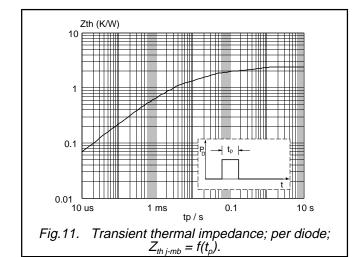


1.0 10 100 100 100 Fig.10. Maximum Q_s at $T_i = 25$ °C; per diode

100 Qs/nC

10





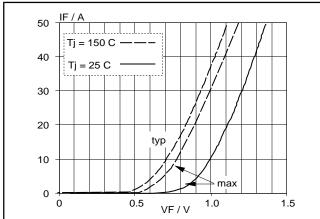
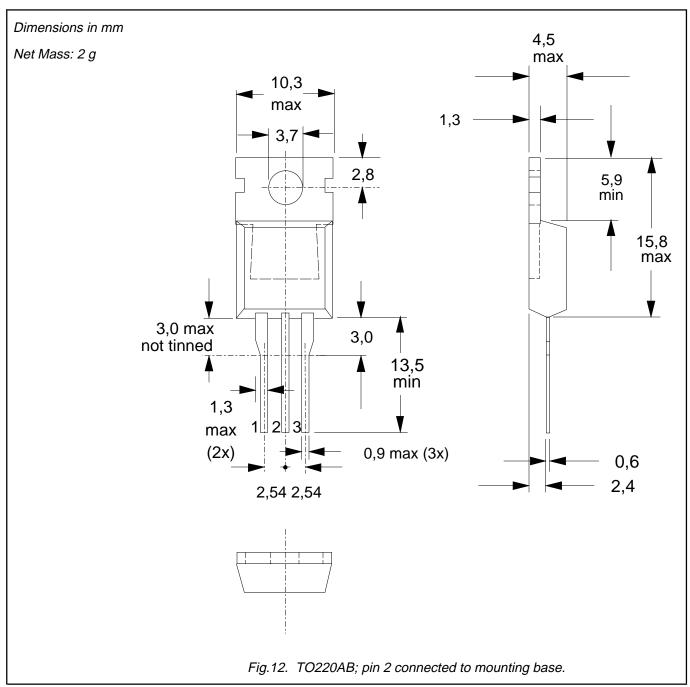


Fig.9. Typical and maximum forward characteristic $I_F = f(V_F)$; parameter T_j

Rectifier diodes ultrafast, rugged BYV42E series

MECHANICAL DATA



- Accessories supplied on request: refer to mounting instructions for TO220 envelopes.
 Epoxy meets UL94 V0 at 1/8".

Rectifier diodes ultrafast, rugged

BYV42E series

DEFINITIONS

Data sheet status					
Objective specification	This data sheet contains target or goal specifications for product development.				
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.				
Product specification	This data sheet contains final product specifications.				
Product specification	This data sheet contains final product specifications.				

Limiting values

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

© Philips Electronics N.V. 1994

All rights are reserved. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner.

The information presented in this document does not form part of any quotation or contract, it is believed to be accurate and reliable and may be changed without notice. No liability will be accepted by the publisher for any consequence of its use. Publication thereof does not convey nor imply any license under patent or other industrial or intellectual property rights.

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.